

Silicon Diode

EGL41D

200V / 1A

DATASHEET

from

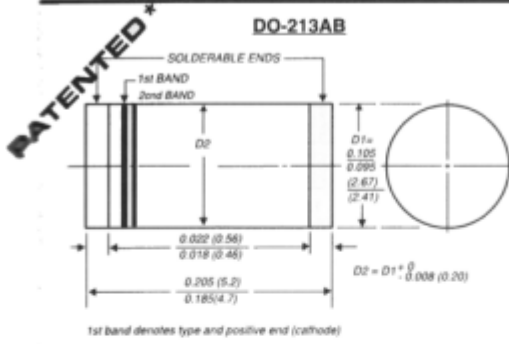
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OEM – General Semiconductor

Source: General Semiconductor Databook 1998

BYM12-50 THRU BYM12-400 EGL41A THRU EGL41G

SURFACE MOUNT GLASS PASSIVATED JUNCTION FAST EFFICIENT RECTIFIER
Reverse Voltage - 50 to 400 Volts Forward Current - 1.0 Ampere



1st band denotes type and positive end (cathode)
 Dimensions in inches and (millimeters)
 * Glass-plastic encapsulation is covered by
 Patent No. 3,996,602 and brazed-lead assembly to Patent No. 3,930,306



FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ Capable of meeting environmental standards of MIL-S-19500
- ◆ For surface mount applications
- ◆ High temperature metallurgically bonded construction
- ◆ Glass passivated cavity-free junction
- ◆ Fast switching for high efficiency
- ◆ High temperature soldering guaranteed:
 450°C/5 seconds at terminals. Complete device submersible temperature of 260°C for 10 seconds in solder bath



MECHANICAL DATA

Case: JEDEC DO-213AB molded plastic over glass body
Terminals: Plated terminals, solderable per MIL-STD-750, Method 2026
Polarity: Two bands indicate cathode end -1st band denotes device type and 2nd band denotes repetitive peak reverse voltage rating
Mounting Position: Any
Weight: 0.116 ounce, 0.0046 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

| | SYMBOLS | BYM12 -50 | BYM12 -100 | BYM12 -150 | BYM12 -200 | BYM12 -300 | BYM12 -400 | UNITS |
|--|-----------------------------------|--------------|---------------|---------------|---------------|---------------|---------------|-------|
| Fast efficient device: 1st band is green | | EGL41A | EGL41B | EGL41C | EGL41D | EGL41F | EGL41G | |
| Polarity color bands (2nd band) | | GRAY | RED | PINK | ORANGE | BROWN | YELLOW | |
| Maximum repetitive peak reverse voltage | VRRM | 50 | 100 | 150 | 200 | 300 | 400 | Volts |
| Maximum RMS voltage | VRMS | 35 | 70 | 105 | 140 | 210 | 280 | Volts |
| Maximum DC blocking voltage | VDC | 50 | 100 | 150 | 200 | 300 | 400 | Volts |
| Maximum average forward rectified current at T _T =75°C | I(AV) | 1.0 | | | | | | Amp |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I _{FSM} | 30.0 | | | | | | Amps |
| Maximum instantaneous forward voltage at 1.0A | V _F | | | | 1.0 | 1.25 | | Volts |
| Maximum DC reverse current at rated DC blocking voltage | I _R | | | | 5.0 | | | μA |
| | | | | | 50.0 | | | |
| Maximum reverse recovery time (NOTE 1) | t _{rr} | 50.0 | | | | | | ns |
| Typical junction capacitance (NOTE 2) | C _J | | | | 20.0 | 14.0 | | pF |
| Maximum thermal resistance (NOTE 3) | R _{θJA} | 60.0 | | | | | | °C/W |
| (NOTE 4) | R _{θJT} | 30.0 | | | | | | |
| Operating junction and storage temperature range | T _J , T _{STG} | -65 to +175 | | | | | | °C |

NOTES:
 (1) Reverse recovery test conditions: I_F=0.5A, I_R=1.0A, I_S=0.25A
 (2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts
 (3) Thermal resistance from junction to ambient, 0.24 x 0.24" (6.0 x 6.0mm) copper pads to each terminal
 (4) Thermal resistance from junction to terminal, 0.24 x 0.24" (6.0 x 6.0mm) copper pads to each terminal

RATINGS AND CHARACTERISTIC CURVES BYM12-50 THRU BYM12-400, EGL41A THRU EGL41G

